

N-Channel Enhancement Mode MOSFET

1. Product Information

1.1 Features

- ☑ Advanced trench cell design
- ☑ Low Thermal Resistance

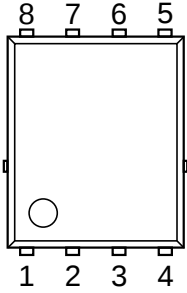
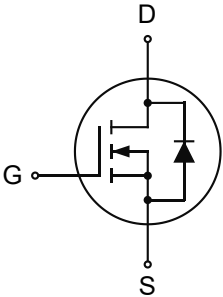
1.2 Applications

- ☑ Motor drivers
- ☑ DC/DC Converter

1.3 Quick reference

- ☑ $BV \geq 150V$
- ☑ $P_{tot} \leq 140W$
- ☑ $I_D \leq 60A$
- ☑ $R_{DS(ON)} \leq 13m\Omega @ V_{GS} = 10V$
- ☑ $R_{DS(ON)} \leq 18m\Omega @ V_{GS} = 6V$

2. Pin Description

Pin	Description	Simplified Outline	Symbol
1,2,3	Source	 Top View PDFN5x6-8L	
4	Gate		
5,6,7,8	Drain		

3. Limiting Values

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	Drain-Source Voltage	$T_C=25^{\circ}C$	150	-	V
V_{GS}	Gate-Source Voltage	$T_C=25^{\circ}C$	-	± 25	V
I_D^*	Drain Current	$T_C=25^{\circ}C, V_{GS}=10V$	-	60	A
I_D^*	Drain Current	$T_C=100^{\circ}C, V_{GS}=10V$	-	38.4	A
$I_{DM}^{*,**}$	Pulsed Source Current	$T_C=25^{\circ}C, V_{GS}=10V$	-	120	A
P_{tot}^*	Total Power Dissipation	$T_C=25^{\circ}C$	-	140	W
T_{stg}	Storage Temperature		-55	150	$^{\circ}C$
T_J	Junction Temperature		-	150	$^{\circ}C$
I_S	Diode Forward Current	$T_C=25^{\circ}C$	-	60	A
$R_{\theta JA}^*$	Thermal Resistance-Junction to Ambient		-	42	$^{\circ}C/W$
$R_{\theta JC}^*$	Thermal Resistance-Junction to Case		-	1.3	

Notes:

- * Surface Mounted on 1 in² pad area, $t \leq 10$ sec
- ** Pulse width $\leq 1\mu s$, duty cycle $\leq 2\%$
- *** Limited by bonding wire

4. Marking Information

Product Name	Marking
KJ1315G	1315 YWWXXX YWWXXX Date Code

5. Ordering Code

Product Name	Package	Reel Size	Tape width	Quantity	Note
KJ1315G	PDFN5x6-8L			5000	

Note:

KUAIJIEIXIN defines "Green" as lead-free (RoHS compliant) and halogen free (Br or Cl does not exceed 900 ppm by weight in homogeneous material and total of Br and Cl does not exceed 1500 ppm by weight; Follow IEC 61249-2-21 and IPC/JEDEC J-STD-020C)

6. Electrical Characteristics (T_A=25°C Unless Otherwise Noted)

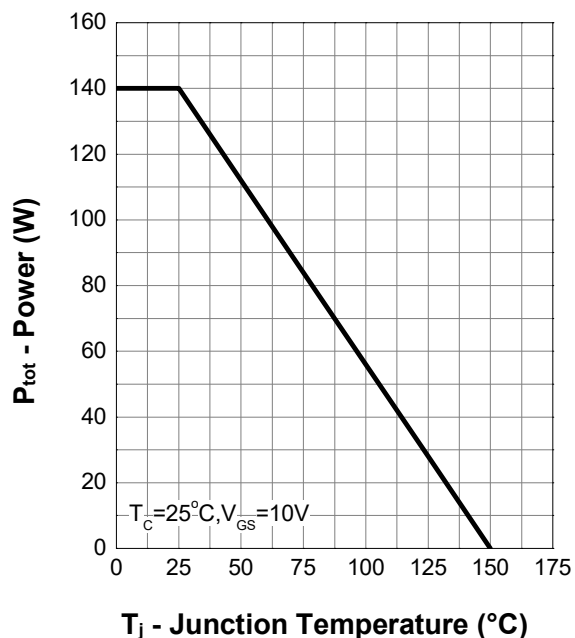
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static Characteristics						
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _{DS} =250μA	150	-	-	V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _{DS} =250μA	2.0	-	4.0	V
I _{DSS}	Zero Gate Voltage Source Current	V _{DS} =120V, V _{GS} =0V	-	-	1	μA
		T _J =85°C	-	-	30	μA
I _{GSS}	Gate Leakage Current	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA
R _{DS(ON)} ^a	Drain-Source On-State Resistance	V _{GS} =10V, I _D =20A	-	12	13	mΩ
		V _{GS} =6V, I _D =10A	-	15	18	mΩ
Diode Characteristics						
V _{SD} ^a	Diode Forward Voltage	I _{SD} =20A, V _{GS} =0V	-	-	1.3	V
t _{rr}	Reverse Recovery Time	I _{DS} =20A, V _{GS} =0V dI _{SD} /dt=100A/μs	-	86	-	ns
Q _{rr}	Reverse Recovery Charge		-	310	-	nC
Dynamic Characteristics ^b						
C _{iss}	Input Capacitance	V _{GS} =0V, V _{DS} =75V Frequency=1MHz	-	2881	-	pF
C _{oss}	Output Capacitance		-	207	-	
C _{rss}	Reverse Transfer Capacitance		-	23	-	
t _{d(on)}	Turn-on Delay Time	V _{DS} =75V, V _{GEN} =10V, R _G =45Ω, R _L =3.75Ω, I _{DS} =20A	-	15	-	ns
t _r	Turn-on Rise Time		-	34	-	
t _{d(off)}	Turn-off Delay Time		-	30	-	
t _f	Turn-off Fall Time		-	26	-	
Gate Charge Characteristics ^b						
Q _g	Total Gate Charge	V _{DS} = 75 V, V _{GS} = 10 V, I _{DS} = 20 A	-	30.5	-	nC
Q _{gs}	Gate-Source Charge		-	16.1	-	
Q _{gd}	Gate-Drain Charge		-	10.8	-	

Notes:

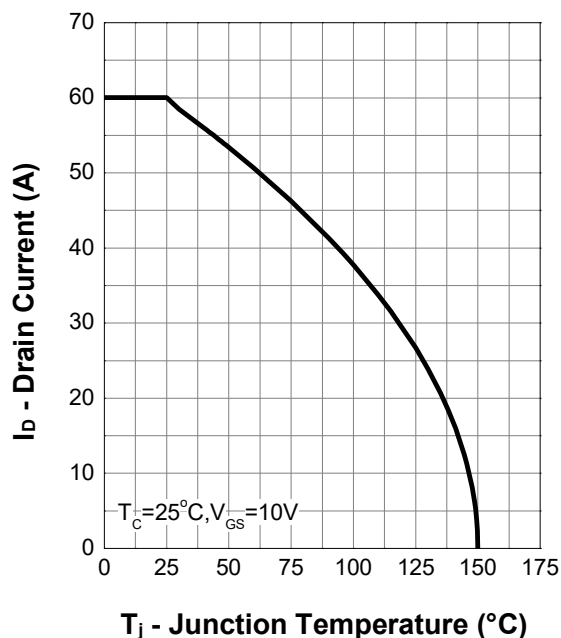
- Pulse test; pulse width ≤ 300μs, duty cycle ≤ 2%
- Guaranteed by design, not subject to production testing

7. Typical Characteristics

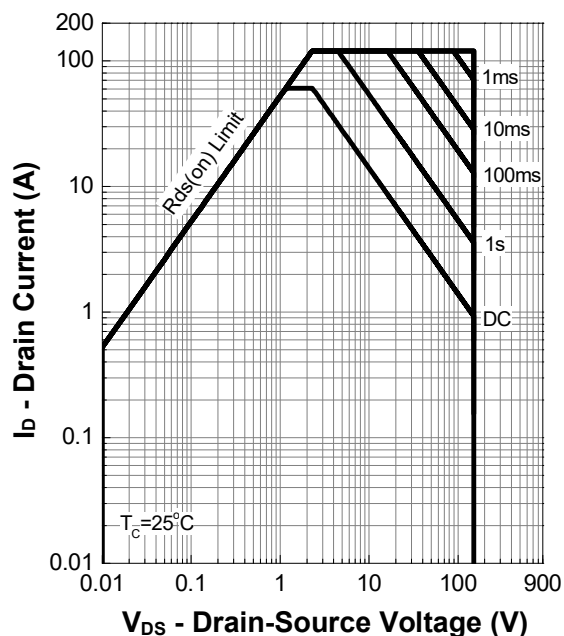
Power Capability



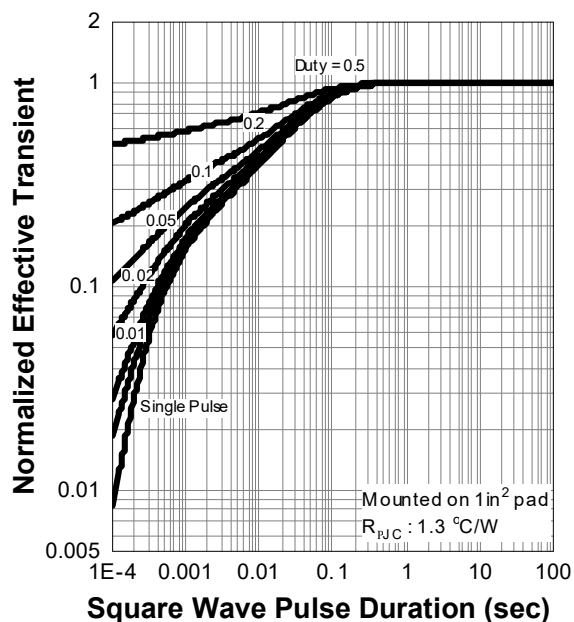
Current Capability



Safe Operation Area

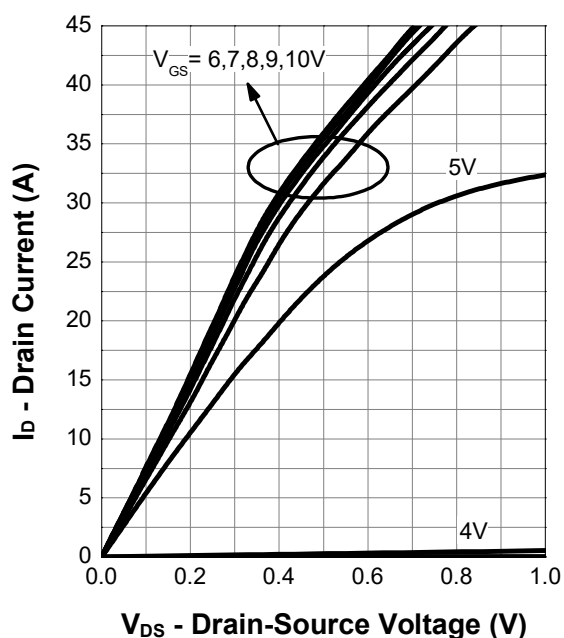


Transient Thermal Impedance

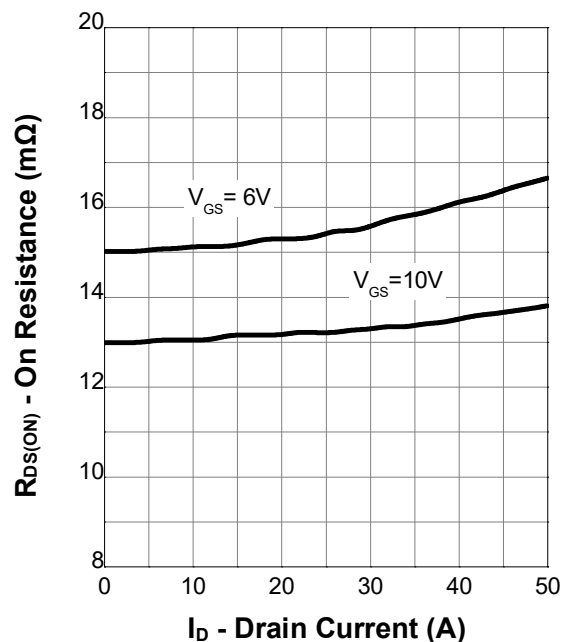


7. Typical Characteristics (cont.)

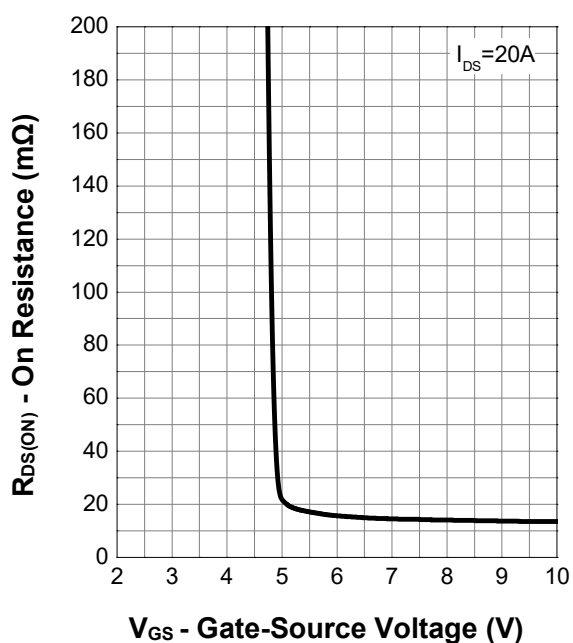
Output Characteristics



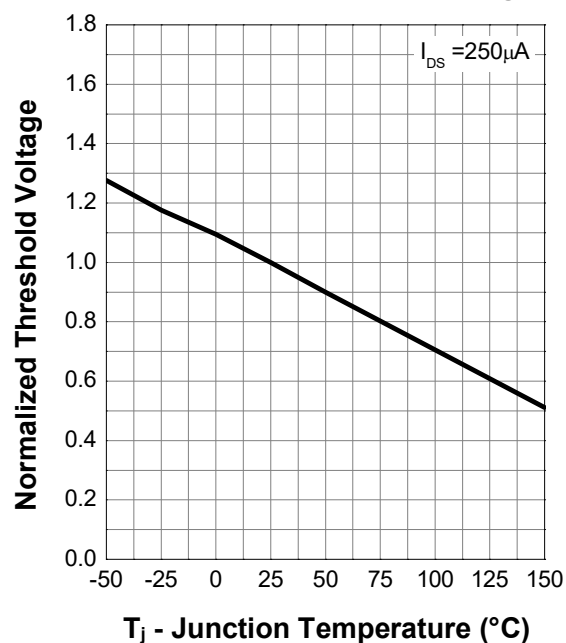
On Resistance



Transfer Characteristics

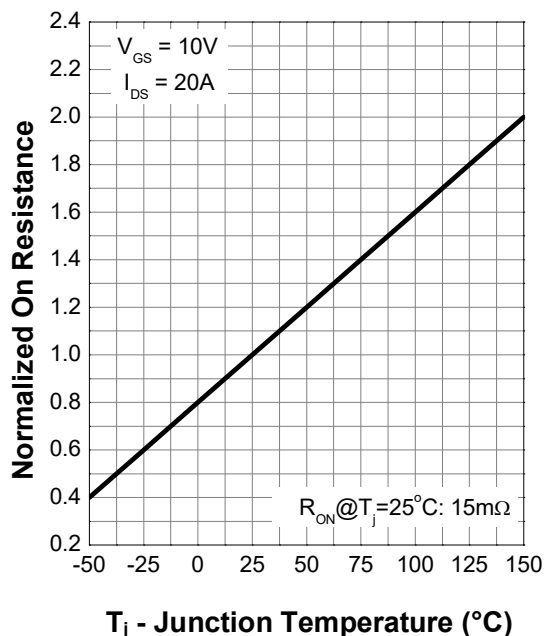


Normalized Threshold Voltage

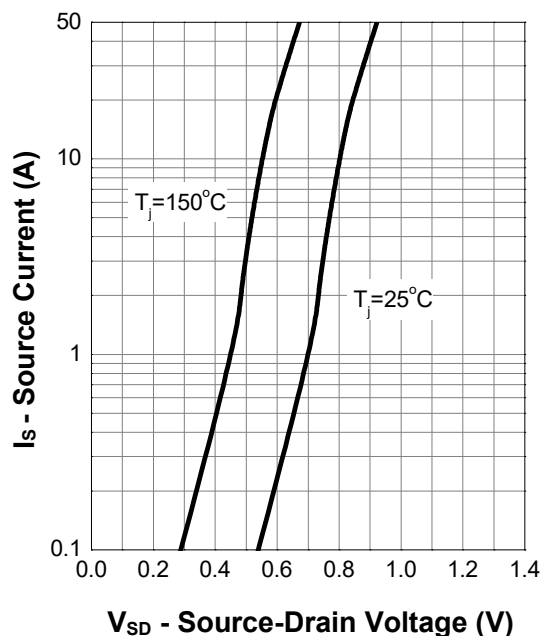


7. Typical Characteristics (cont.)

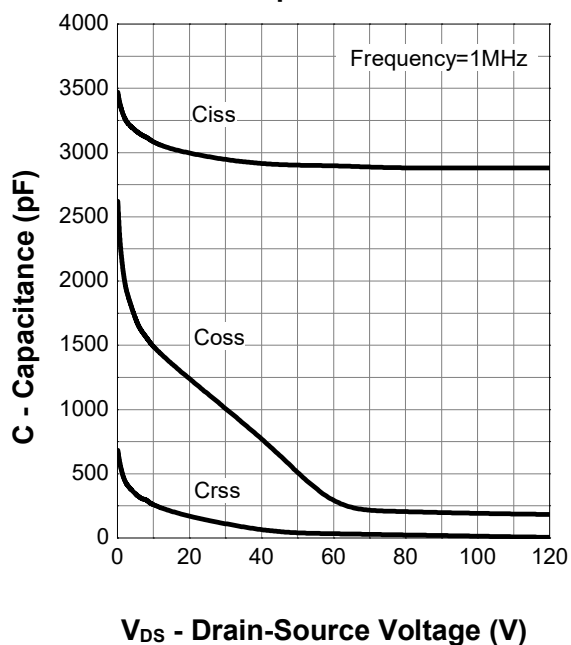
Normalized On Resistance



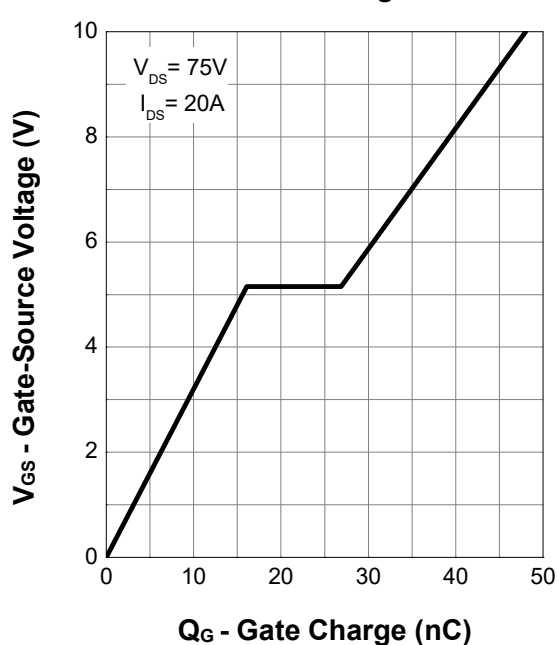
Diode Forward Current



Capacitance

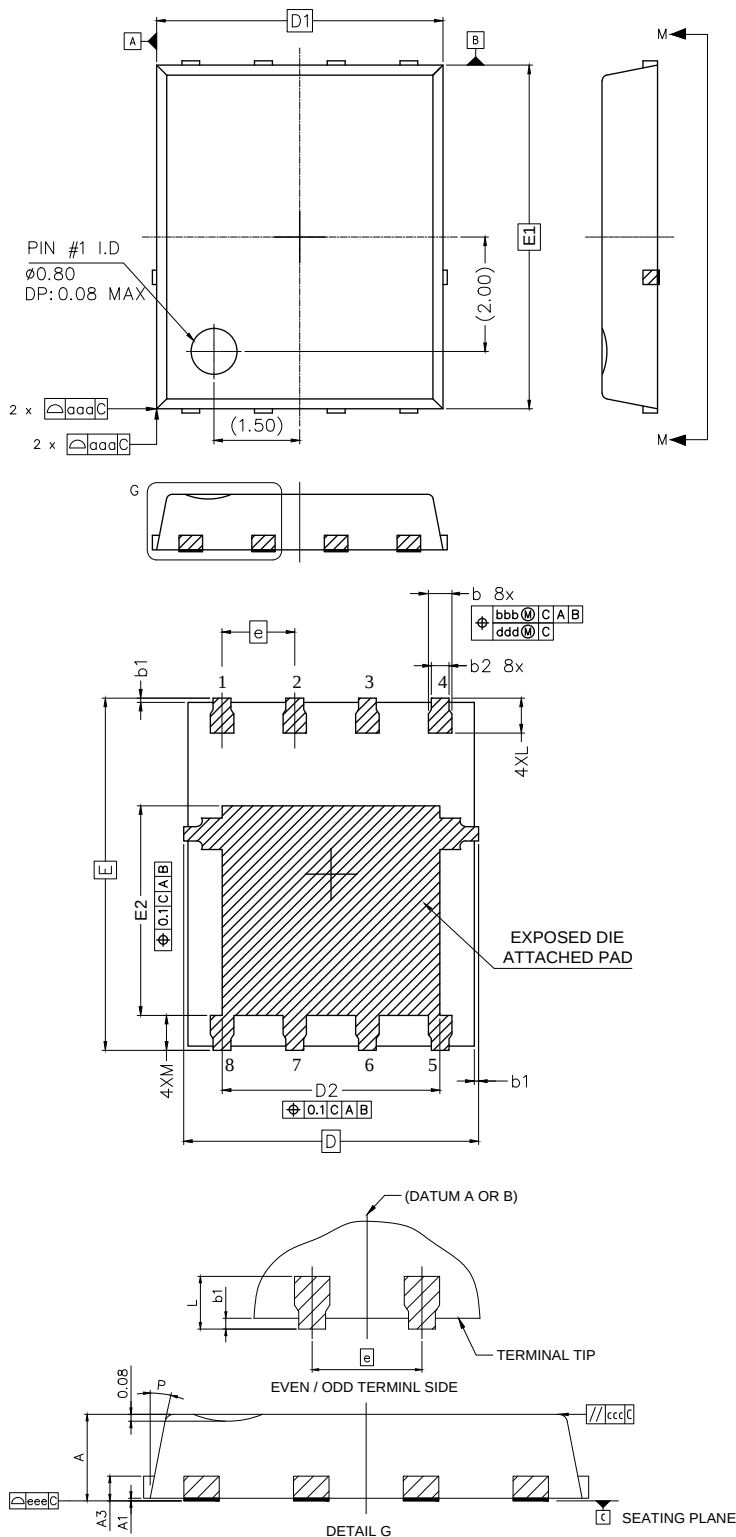


Gate Charge



8. Package Dimensions

PDFN5x6-8L Package



Symbol	Dimensions In Millimeters	
	MIN.	MAX.
A	0.95	1.05
A1	0.00	0.05
A3	0.25 REF	
b	0.31	0.51
b1	0.03	0.13
b2	0.21	0.41
D	5.15 BSC	
D1	5.00 BSC	
D2	3.70	3.90
E	6.15 BSC	
E1	6.00 BSC	
E2	3.56	3.76
e	1.27 BSC	
L	0.51	0.71
M	0.51	0.71
P	10°	12°
aaa	0.10	
bbb	0.10	
ccc	0.10	
ddd	0.05	
eee	0.08	